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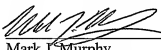
CPA GLOBAL NORTH AMERICA LLC  
2318 Mill Road  
12<sup>th</sup> Floor  
Alexandria, VA 22314

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in the following listed application(s) or patent(s) for which the issue fee has been paid.

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Respectfully Submitted,

  
Mark J. Murphy  
Registration No. 34,225  
Date: May 27, 2011

Husch Blackwell LLP  
120 South Riverside Plaza  
Suite 2200  
Chicago, Illinois 60606  
(312) 655-1500

Customer No: 24628



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**Higaki et al.**

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(54) **SEMICONDUCTOR DEVICE**

(56)

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(75) **Inventors:** Yoshinari Higaki, Hiroshima (JP);  
 Masayuki Sakakura, Kanagawa (JP);  
 Shunpei Yamazaki, Tokyo (JP)

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(\*) **Notice:** Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 78 days.

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*Primary Examiner*—Tina M Wong

(74) *Attorney, Agent, or Firm*—Husch Blackwell LLP Welsh Katz

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## ABSTRACT

**PCT Pub. Date:** Mar. 23, 2006

It is an object of the present invention to connect a wiring, an electrode, or the like formed with two incompatible films (an ITO film and an aluminum film) without increasing the cross-sectional area of the wiring and to achieve lower power consumption even when the screen size becomes larger. The present invention provides a two-layer structure including an upper layer and a lower layer having a larger width than the upper layer. A first conductive layer is formed with Ti or Mo, and a second conductive layer is formed with aluminum (pure aluminum) having low electric resistance over the first conductive layer. A part of the lower layer projected from the end section of the upper layer is bonded with ITO.

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**G02F 1/136** (2006.01)

(52) **U.S. Cl.** ..... 349/46; 349/42

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 See application file for complete search history.

**28 Claims, 14 Drawing Sheets**

